

MAX4638/MAX4639

3.5Ω, Single 8:1 and Dual 4:1, Low-Voltage Analog Multiplexers

General Description

The MAX4638/MAX4639 are single 8:1 and dual 4:1 CMOS analog multiplexers/demultiplexers (muxes/demuxes). Each mux operates from a single +1.8V to +5V supply or dual ±2.5V supplies. These devices feature 3.5Ω on-resistance (R_{ON}) when powered with a single +5V supply and have -75dB off-isolation and -85dB crosstalk from the output to each off channel. The switching times are 18ns t_{ON} and 7ns t_{OFF} . They feature a -3dB 85MHz bandwidth and a guaranteed 0.25nA leakage current at +25°C.

A +1.8V to +5.5V operating range makes the MAX4638/MAX4639 ideal for battery-powered, portable instruments. All channels guarantee break-before-make switching. These parts feature bidirectional operation and can handle Rail-to-Rail® analog signals. All control inputs are TTL/CMOS-logic compatible. Decoding is in standard BCD format, and an enable input is provided to simplify cascading of devices. These devices are available in small 16-pin TQFN, TSSOP, and SO packages, as well as a 20-pin TQFN package.

Applications

Automatic Test Equipment
 Low-Voltage Data-Acquisition Systems
 Audio and Video Signal Routing
 Medical Equipment
 Battery-Powered Equipment
 Relay Replacement

Features

- ◆ **Guaranteed R_{ON}**
 3.5Ω (+5V or ±2.5V Supplies)
 6Ω (+3V Supply)
- ◆ **Guaranteed 0.4Ω R_{ON} Match Between Channels**
- ◆ **Guaranteed 1Ω R_{ON} Flatness Over Signal Range**
- ◆ **Guaranteed Low Leakage Currents**
 0.25nA at +25°C
- ◆ **Switching Times: t_{ON} = 18ns, t_{OFF} = 7ns**
- ◆ **+1.8V to +5.5V Single-Supply Operation**
 ±2.5V Dual-Supply Operation
- ◆ **Rail-to-Rail Signal Handling**
- ◆ **TTL/CMOS-Logic Compatible**
- ◆ **Crosstalk: -80dB (1MHz)**
- ◆ **Off-Isolation: -60dB (10MHz)**

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX4638ETE+T	-40°C to +85°C	16 TQFN-EP* (4 × 4)
MAX4638EUE+T	-40°C to +85°C	16 TSSOP
MAX4638ESE+T	-40°C to +85°C	16 SO
MAX4638ETP+T	-40°C to +85°C	20 TQFN-EP* (4 × 4)

+Denotes a lead(Pb)-free/RoHS-compliant package.

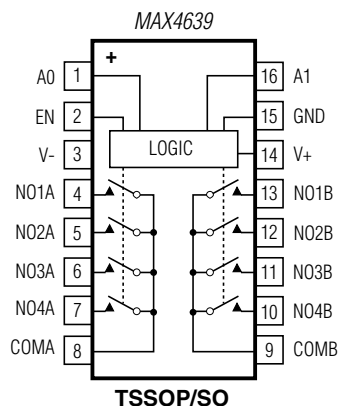
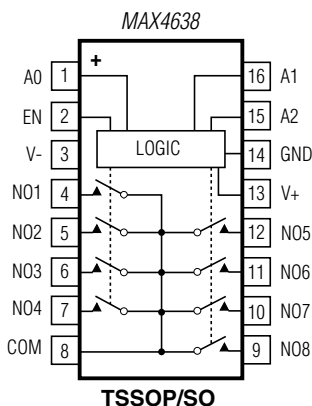
T = Tape and reel.

*EP = Exposed pad.

Ordering Information continued at end of data sheet.

Pin Configurations/Functional Diagrams

TOP VIEW



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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ABSOLUTE MAXIMUM RATINGS

(Voltages Referenced to GND)

V+ to V-	+6V
V+, A ₋ , EN	-0.3V to +6V
V-	+0.3V to -6V
NO ₋ , COM ₋ (Note 1)	-0.3V to (V+ + 0.3V)
Continuous Current A ₋ , EN	±30mA
Continuous Current NO ₋ , COM ₋	±100mA
Peak Current (NO ₋ , COM ₋) (pulsed at 1ms, 10% duty cycle)	±200mA

Continuous Power Dissipation (T_A = +70°C)

TQFN (derate 16.9mW/°C above +70°C)	1349mW
TSSOP (derate 9.4mW/°C above +70°C)	754.7mW
SO (derate 8.70mW/°C above +70°C)	696mW
Operating Temperature Range	
MAX463_E_E	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

Note 1: Signals on COM₋, NO₋ exceeding V+ or V- are clamped by internal diodes. A₋ and EN are clamped only to V- and can exceed V+ up to their maximum ratings. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—+5V Single Supply

(V+ = +5V ±10%, V- = 0, V_{IH} = +2.4V, V_{IL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM-} , V _{NO-}			0		V+	V
On-Resistance	R _{ON}	V+ = +4.5V, I _{COM-} = 10mA, V _{NO-} = +3.5V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	2.5		3.5 4.5	Ω
On-Resistance Match Between Channels (Notes 4, 5)	ΔR _{ON}	V+ = +4.5V, I _{COM-} = 10mA, V _{NO-} = +3.5V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	0.1		0.4 0.5	Ω
On-Resistance Flatness (Note 6)	R _{FLAT(ON)}	V+ = +4.5V; I _{COM-} = 10mA; V _{NO-} = +1V, +2V, +3.5V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	0.75		1 1.2	Ω
NO_ Off-Leakage Current (Note 7)	I _{NO-(OFF)}	V+ = +5.5V; V _{COM-} = +1V, +4.5V; V _{NO-} = +4.5V, +1V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	-0.25 -0.35	±0.01	0.25 0.35	nA
COM_ Off-Leakage Current (Note 7)	I _{COM-(OFF)}	V+ = +5.5V; V _{COM-} = +1V, +4.5V; V _{NO-} = +4.5V, +1V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	-0.25 -0.75	±0.01	0.25 0.75	nA
COM_ On-Leakage Current (Note 7)	I _{COM-(ON)}	V+ = +5.5V; V _{COM-} = +1V, +4.5V; V _{NO-} = +1V, +4.5V, or unconnected	T _A = +25°C T _A = T _{MIN} to T _{MAX}	-0.25 -0.75	±0.01	0.25 0.75	nA
DIGITAL I/O							
Input Logic High	V _{IH}			2.4			V
Input Logic Low	V _{IL}					0.8	V
Input Leakage Current	I _{IH} , I _{IL}	V _{IN-} = 0 or V+		-0.1	0.005	0.1	μA
Digital Input Capacitance	C _{IN}			2			pF
DYNAMIC							
Transition Time (Note 7)	t _{TRANS}	RL = 100Ω, CL = 35pF, V _{NO1} = +3V or 0, V _{NO8} = 0 or +3V, Figure 2	T _A = +25°C T _A = T _{MIN} to T _{MAX}	14		18 20	ns

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ELECTRICAL CHARACTERISTICS—+5V Single Supply (continued)

(V+ = +5V ±10%, V- = 0, V_{IH} = +2.4V, V_{IL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS
Break-Before-Make (Note 7)	t _{BBM}	R _L = 100Ω, C _L = 35pF, V _{NO_} = +3V, Figure 3	T _A = +25°C		8		ns	
			T _A = T _{MIN} to T _{MAX}		1			
Enable Turn-On Time (Note 7)	t _{ON(EN)}	R _L = 100Ω, C _L = 35pF, V _{NO1} = +3V, V _{NO2} to V _{NO8} = 0, Figure 4	T _A = +25°C		14	18	ns	
			T _A = T _{MIN} to T _{MAX}		20			
Enable Turn-Off Time (Note 7)	t _{OFF(EN)}	R _L = 100Ω, C _L = 35pF, V _{NO1} = +3V, V _{NO2} to V _{NO8} = 0, Figure 4	T _A = +25°C		5	7	ns	
			T _A = T _{MIN} to T _{MAX}		8			
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, C _L = 5pF, 50Ω in and out, Figure 6	MAX4638	T _A = +25°C	50		MHz	
			MAX4639	T _A = +25°C	85			
Charge Injection	Q	V _{GEN} = +2.5V, R _{GEN} = 0, C _L = 1.0nF, Figure 5		T _A = +25°C	13		pC	
NO_ Off-Capacitance	C _{NO_(OFF)}	V _{NO_} = 0V, f = 1MHz, Figure 8		T _A = +25°C	9		pF	
COM_ Off-Capacitance	C _{COM_(OFF)}	V _{COM_} = 0V, f = 1MHz, Figure 8	MAX4638	T _A = +25°C	40		pF	
			MAX4639	T _A = +25°C	20			
Switch On-Capacitance	C _(ON)	V _{COM_} = V _{NO_} = 0V, f = 1MHz, Figure 8	MAX4638	T _A = +25°C	54		pF	
			MAX4639	T _A = +25°C	34			
Off-Isolation (Note 8)	V _{ISO}	C _L = 5pF, R _L = 50Ω, f = 1MHz, V _{NO_} = 1V _{RMS} , Figure 6	T _A = +25°C		-55		dB	
		C _L = 5pF, R _L = 50Ω, f = 10MHz, V _{NO_} = 1V _{RMS} , Figure 6	T _A = +25°C		-75			
Crosstalk (Note 9)	V _{CT}	C _L = 5pF, R _L = 50Ω, f = 10MHz, V _{NO_} = 1V _{RMS} , Figure 7	T _A = +25°C		-65		dB	
		C _L = 5pF, R _L = 50Ω, f = 1MHz, V _{NO_} = 1V _{RMS} , Figure 7	T _A = +25°C		-85			
Total Harmonic Distortion	THD	R _L = 600Ω, R _{FLAT(ON)} /R _L		T _A = +25°C	0.5		%	
SUPPLY								
Positive Supply Current	I+	V+ = +5.5V, V _{IN} = 0 or V+			0.001	1.0	μA	

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ELECTRICAL CHARACTERISTICS—+3.0V Single Supply

(V+ = +2.7V to +3.3V, V- = 0, VIH = +2.0V, VIL = +0.4V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at V+ = +3V and TA = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM_} , V _{NO_}			0		V+	V
On-Resistance	R _{ON}	I _{COM_} = 10mA, V _{NO_} = +1.7V	T _A = +25°C	4.5	6		Ω
			T _A = T _{MIN} to T _{MAX}			8	
On-Resistance Match Between Channels (Notes 4, 5)	ΔR _{ON}	I _{COM_} = 10mA, V _{NO_} = +1.7V	T _A = +25°C	0.25	0.6		Ω
			T _A = T _{MIN} to T _{MAX}			0.8	
On-Resistance Flatness (Note 6)	R _{FLAT(ON)}	I _{COM_} = 10mA; V _{NO_} = +1.5V, +1.7V, +1.9V	T _A = +25°C	1	2		Ω
			T _A = T _{MIN} to T _{MAX}			2.5	
NO_ Off-Leakage Current (Note 7)	I _{NO_(OFF)}	V+ = +3.3V; V _{COM_} = +1V, +3V; V _{NO_} = +3V, +1V	T _A = +25°C	-0.25	±0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	-0.35		0.35	
COM_ Off-Leakage Current (Note 7)	I _{COM_(OFF)}	V+ = +3.3V; V _{COM_} = +1V, +3V; V _{NO_} = +3V, +1V	T _A = +25°C	-0.25	±0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	-0.35		0.35	
COM_ On-Leakage Current (Note 7)	I _{COM_(ON)}	V+ = +3.3V; V _{COM_} = +1V, +3V; V _{NO_} = +1V, +3V, or unconnected	T _A = +25°C	-0.25	±0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	-0.35		0.35	
DIGITAL I/O							
Input Logic High	V _{IH}			2.0			V
Input Logic Low	V _{IL}					0.4	V
Input Leakage Current	I _{IH} , I _{IL}	V _{IN_} = 0 or V+		-0.1	0.005	0.1	μA
Digital Input Capacitance	C _{IN}				2		pF
DYNAMIC							
Transition Time (Note 7)	t _{TRANS}	V _{NO_} = +2V, C _L = 35pF, R _L = 100Ω, Figure 2	T _A = +25°C	16	20		ns
			T _A = T _{MIN} to T _{MAX}			24	
Break-Before-Make (Note 7)	t _{BBM}	V _{NO_} = +2V, C _L = 35pF, R _L = 100Ω, Figure 3	T _A = +25°C	8			ns
			T _A = T _{MIN} to T _{MAX}	1			
Enable Turn-On Time (Note 7)	t _{ON(EN)}	V _{NO_} = +2V, C _L = 35pF, R _L = 100Ω, Figure 4	T _A = +25°C	15	20		ns
			T _A = T _{MIN} to T _{MAX}			24	
Enable Turn-Off Time (Note 7)	t _{OFF(EN)}	V _{NO_} = +2V, C _L = 35pF, R _L = 100Ω, Figure 4	T _A = +25°C	5	9		ns
			T _A = T _{MIN} to T _{MAX}			10	

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ELECTRICAL CHARACTERISTICS—+3.0V Single Supply (continued)

(V+ = +2.7V to +3.3V, V- = 0, V_{IH} = +2.0V, V_{IL} = +0.4V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V+ = +3V and T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
Off-Isolation (Note 8)	V _{ISO}	C _L = 5pF, R _L = 50Ω, f = 10MHz, V _{NO_} = +1V _{RMS} , Figure 6	T _A = +25°C	55		-75	dB
		C _L = 5pF, R _L = 50Ω, f = 1MHz, V _{NO_} = 1V _{RMS} , Figure 6	T _A = +25°C				
Crosstalk (Note 9)	V _{CT}	C _L = 5pF, R _L = 50Ω, f = 10MHz, V _{NO_} = 1V _{RMS} , Figure 7	T _A = +25°C	-65		-85	dB
		C _L = 5pF, R _L = 50Ω, f = 1MHz, V _{NO_} = 1V _{RMS} , Figure 7	T _A = +25°C				
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, 50Ω in and out, Figure 6	MAX4638 T _A = +25°C	50		85	MHz
		MAX4639 T _A = +25°C					
NO_ Off-Capacitance	C _{NO_(OFF)}	V _{NO_} = 0V, f = 1MHz, Figure 8	T _A = +25°C	9			pF
COM_ Off-Capacitance	C _{COM_(OFF)}	V _{COM_} = 0V, f = 1MHz, Figure 8	MAX4638 T _A = +25°C	40		20	pF
		MAX4639 T _A = +25°C					
Switch On-Capacitance	C _(ON)	V _{COM} = V _{NO_} = 0V, f = 1MHz, Figure 8	MAX4638 T _A = +25°C	54		34	pF
		MAX4639 T _A = +25°C					
SUPPLY							
Positive Supply Current	I+	V+ = +3.3V, V _{IN_} = 0 or V+		0.001	1		μA

ELECTRICAL CHARACTERISTICS—±2.5V Dual Supplies

(V+ = +2.5 ±10%, V- = -2.5V ±10%, V_{IH} = +2.0V, V_{IL} = +0.4V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V± = ±2.5V and T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM-} , V _{NO-}			V-		V+	V
On-Resistance	R _{ON}	I _{COM-} = 10mA, V _{NO-} = ±1.5V, V+ = +2.25V, V- = -2.25V	T _A = +25°C	2.5	3.5	Ω	
			T _A = T _{MIN} to T _{MAX}		4.5		
On-Resistance Match Between Channels (Notes 4, 5)	ΔR _{ON}	I _{COM-} = 10mA, V _{NO-} = ±1.5V, V+ = +2.25V, V- = -2.25V	T _A = +25°C	0.2	0.4	Ω	
			T _A = T _{MIN} to T _{MAX}		0.5		

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ELECTRICAL CHARACTERISTICS—±2.5V Dual Supplies (continued)

(V₊ = +2.5 ±10%, V₋ = -2.5V ±10%, V_{IH} = +2.0V, V_{IL} = +0.4V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at V_± = ±2.5V and T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
On-Resistance Flatness (Note 6)	R _{FLAT(ON)}	I _{COM_} = 10mA; V _{NO_} = ±1.5V, 0; V+ = +2.25V; V- = -2.25V	T _A = +25°C	0.75		1	Ω
			T _A = T _{MIN} to T _{MAX}	1.2			
NO_ Off-Leakage Current (Note 7)	I _{NO_ (OFF)}	V+ = +2.75V; V- = -2.75V; V _{COM_} = +1V, +2.5V; V _{NO_} = +2.5V, +1V	T _A = +25°C	-0.25	±0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	0.35			
COM_ Off-Leakage Current (Note 7)	I _{COM_ (OFF)}	V+ = +2.75V; V- = -2.75; V _{COM_} = +1V, +2.5V; V _{NO_} = +2.5V, +1V	T _A = +25°C	-0.25	±0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	0.35			
COM_ On-Leakage Current (Note 7)	I _{COM_ (ON)}	V+ = +2.5V; V- = -2.5; V _{COM_} = +1V, +2.5V; V _{NO_} = +1V, +2.5V, or unconnected	T _A = +25°C	-0.25	±0.01	0.25	nA
			T _A = T _{MIN} to T _{MAX}	0.35			
DIGITAL I/O							
Input Logic High	V _{IH}			2.0			V
Input Logic Low	V _{IL}					0.4	V
Input Leakage Current	I _{IH} , I _{IL}	V _{IN_} = 0 or V+		-0.1	0.005	0.1	μA
Digital Input Capacitance	C _{IN}			2			pF
DYNAMIC							
Transition Time (Note 7)	t _{TRANS}	V _{NO_} = +1.2V, C _L = 35pF, R _L = 100Ω, Figure 2	T _A = +25°C	16		20	ns
			T _A = T _{MIN} to T _{MAX}	24			
Enable Turn-On Time (Note 7)	t _{ON(EN)}	V _{NO_} = +1.2V, C _L = 35pF, R _L = 100Ω, Figure 4	T _A = +25°C	14		18	ns
			T _A = T _{MIN} to T _{MAX}	20			
Enable Turn-Off Time (Note 7)	t _{OFF(EN)}	V _{NO_} = +1.2V, C _L = 35pF, R _L = 100Ω, Figure 4	T _A = +25°C	5		7	ns
			T _A = T _{MIN} to T _{MAX}	8			
Break-Before-Make (Note 7)	t _{BBM}	V _{NO_} = +1.2V, C _L = 35pF, R _L = 100Ω, Figure 3	T _A = +25°C	8			ns
			T _A = T _{MIN} to T _{MAX}	1			

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Parts are tested at +85°C and guaranteed by design over the entire temperature range.

Note 4: ΔRON = RON(MAX) - RON(MIN).

Note 5: ΔRON matching specifications for TQFN packaged parts are guaranteed by design.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Guaranteed by design.

Note 8: Off-Isolation = 20log₁₀ (V_{COM_} / V_{NO_}), V_{COM_} = output, V_{NO_} = input to off switch.

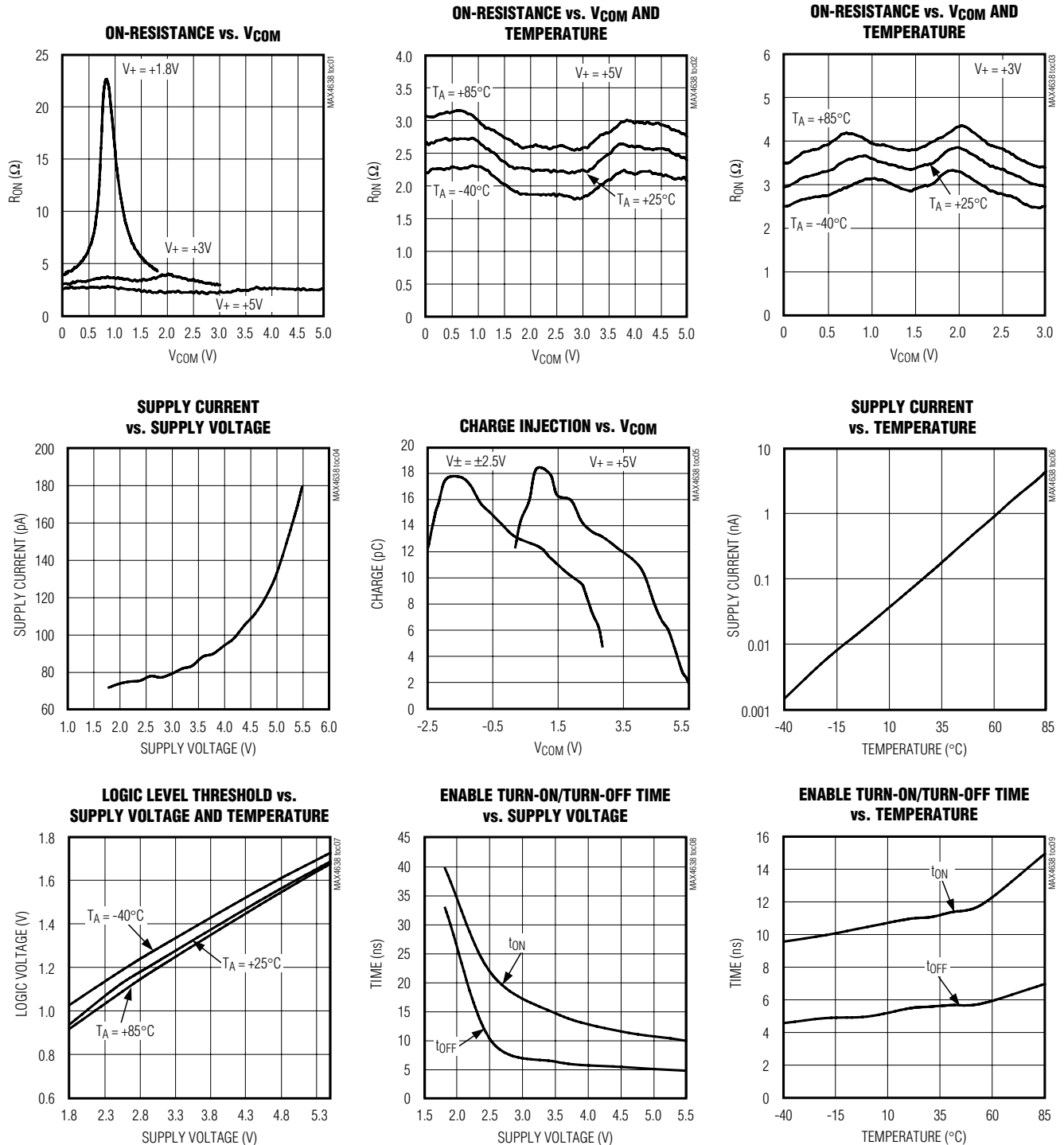
Note 9: Between any two switches.

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Typical Operating Characteristics

($V_+ = +5V$, $V_- = 0V$, $T_A = +25^\circ C$, unless otherwise noted.)

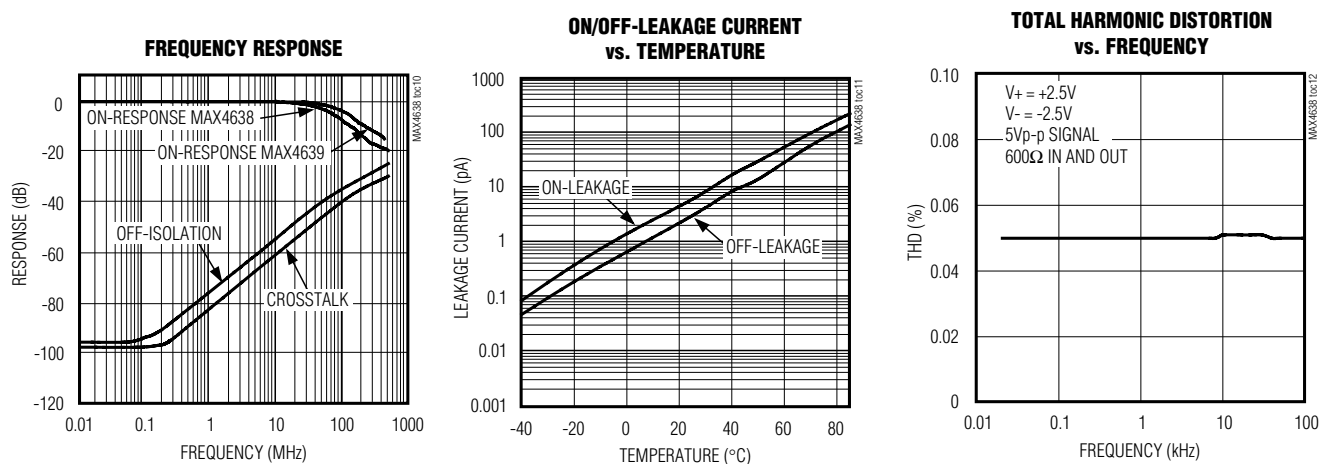


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Typical Operating Characteristics (continued)

(V+ = +5V, V- = 0V, T_A = +25°C, unless otherwise noted.)



Pin Description

PIN						NAME	FUNCTION
MAX4638			MAX4639				
DIP/SO	TQFN-EP		DIP/SO	TQFN-EP			
	16-PIN	20-PIN		16-PIN	20-PIN		
1, 15, 16	15, 13, 14	19, 18, 17	—	—	—	A0, A2, A1	Address Inputs
—	—	—	1, 16	15, 14	19, 17	A0, A1	Address Inputs
2	16	1	2	16	1	EN	Enable
3	1	2	3	1	2	V-	Negative-Supply Voltage Input
4–7	2–5	3–6	—	—	—	NO1–NO4	Bidirectional Analog Inputs
—	—	—	4–7	2–5	3–6	NO1A–NO4A	Bidirectional Analog Inputs
8	6	7	—	—	—	COM	Bidirectional Analog outputs
—	—	—	8, 9	6, 7	7, 9	COMA, COMB	Bidirectional Analog outputs
9–12	7–10	10–13	—	—	—	NO8–NO5	Bidirectional Analog Inputs
—	—	—	10–13	8–11	10–13	NO4B–NO1B	Bidirectional Analog Inputs
13	11	14	14	12	14	V+	Positive-Supply Voltage Input
14	12	15	15	13	15	GND	Ground
—	—	8, 9, 16, 20	—	—	8, 16, 18, 20	N.C.	No Connection. Not internally connected.
—	—	—	—	—	—	EP	Exposed Pad (TQFN Only). Connect EP to V-.

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Test Circuits/Timing Diagrams

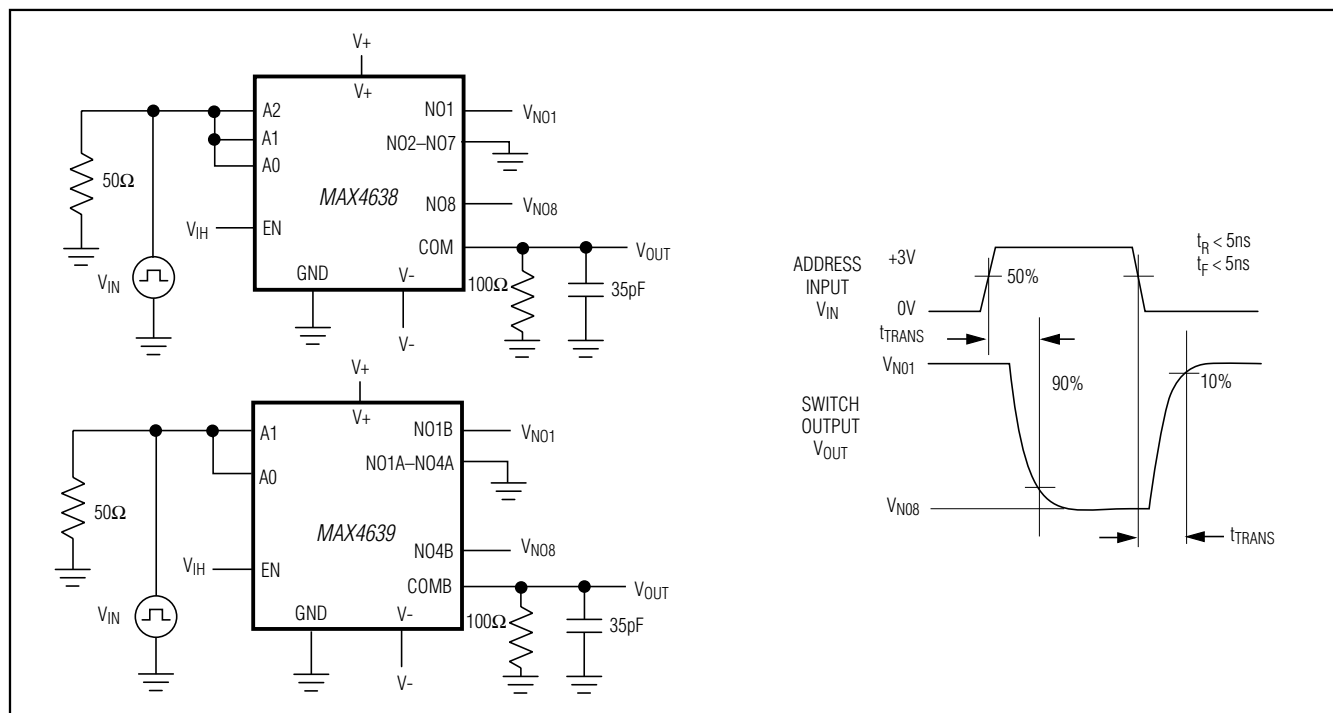


Figure 2. Transition Time

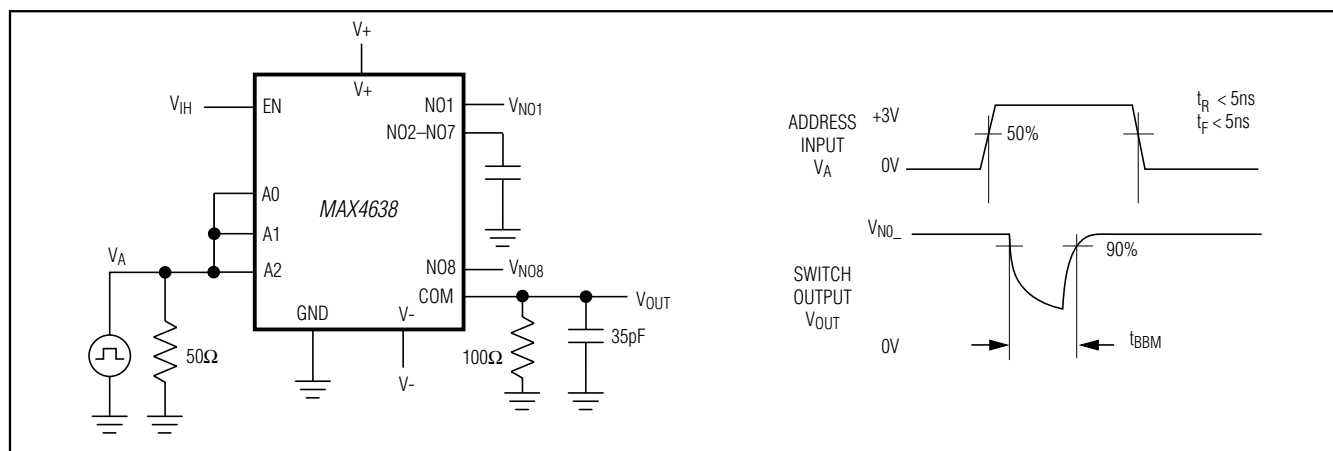


Figure 3. MAX4638 Break-Before-Make Interval

MAX4638/MAX4639

3.5Ω, Single 8:1 and Dual 4:1, Low-Voltage Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

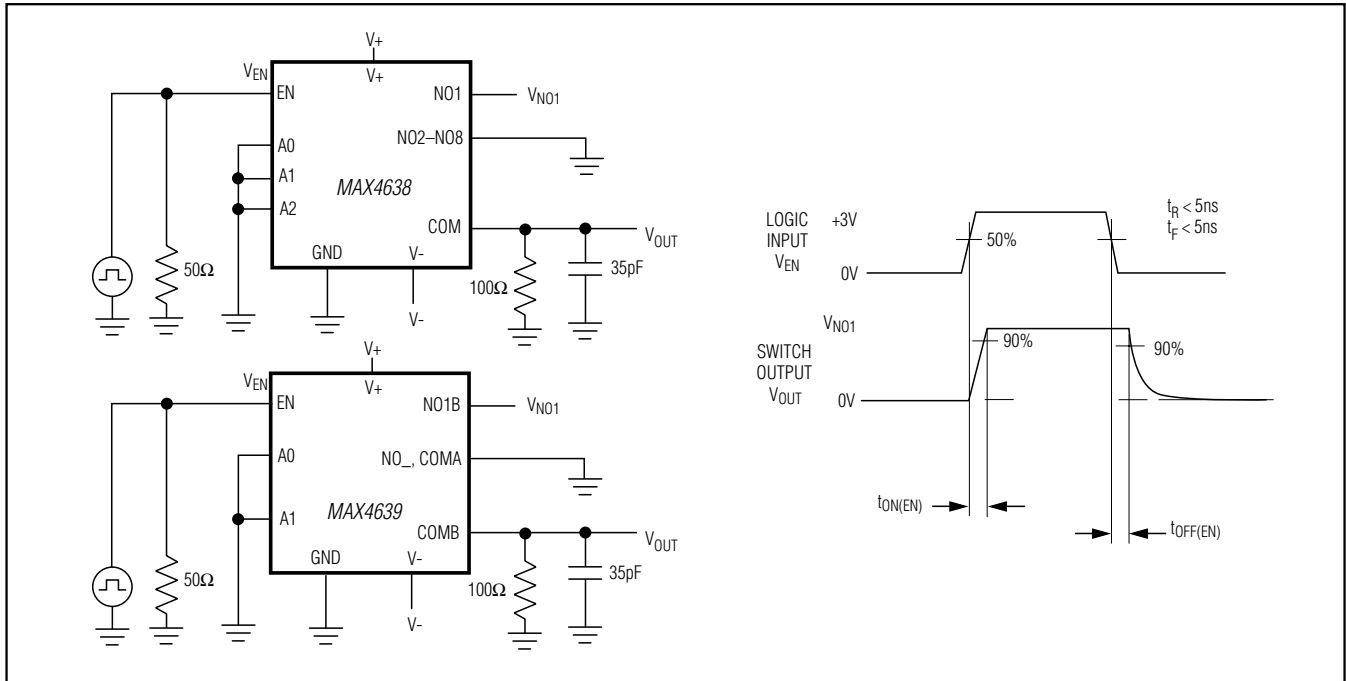


Figure 4. Enable Switching Time

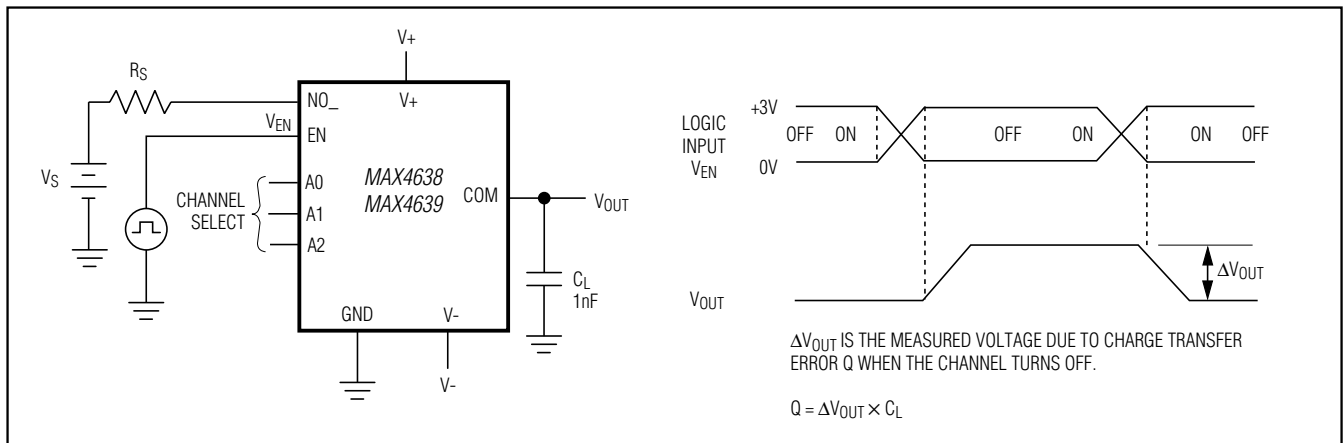


Figure 5. Charge Injection

MAX4638/MAX4639

3.5Ω, Single 8:1 and Dual 4:1, Low-Voltage Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

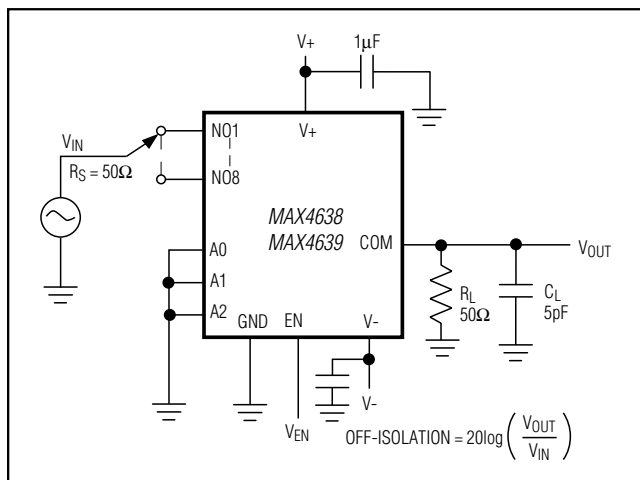


Figure 6. Off-Isolation/On-Channel Bandwidth

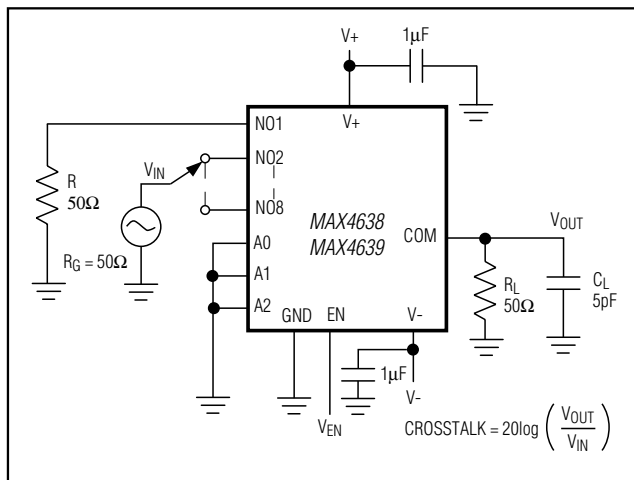


Figure 7. Crosstalk

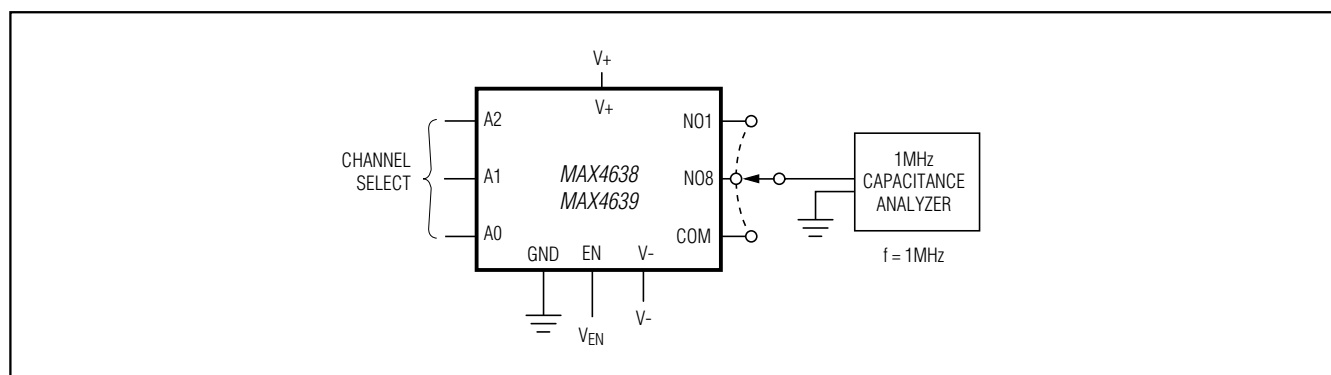
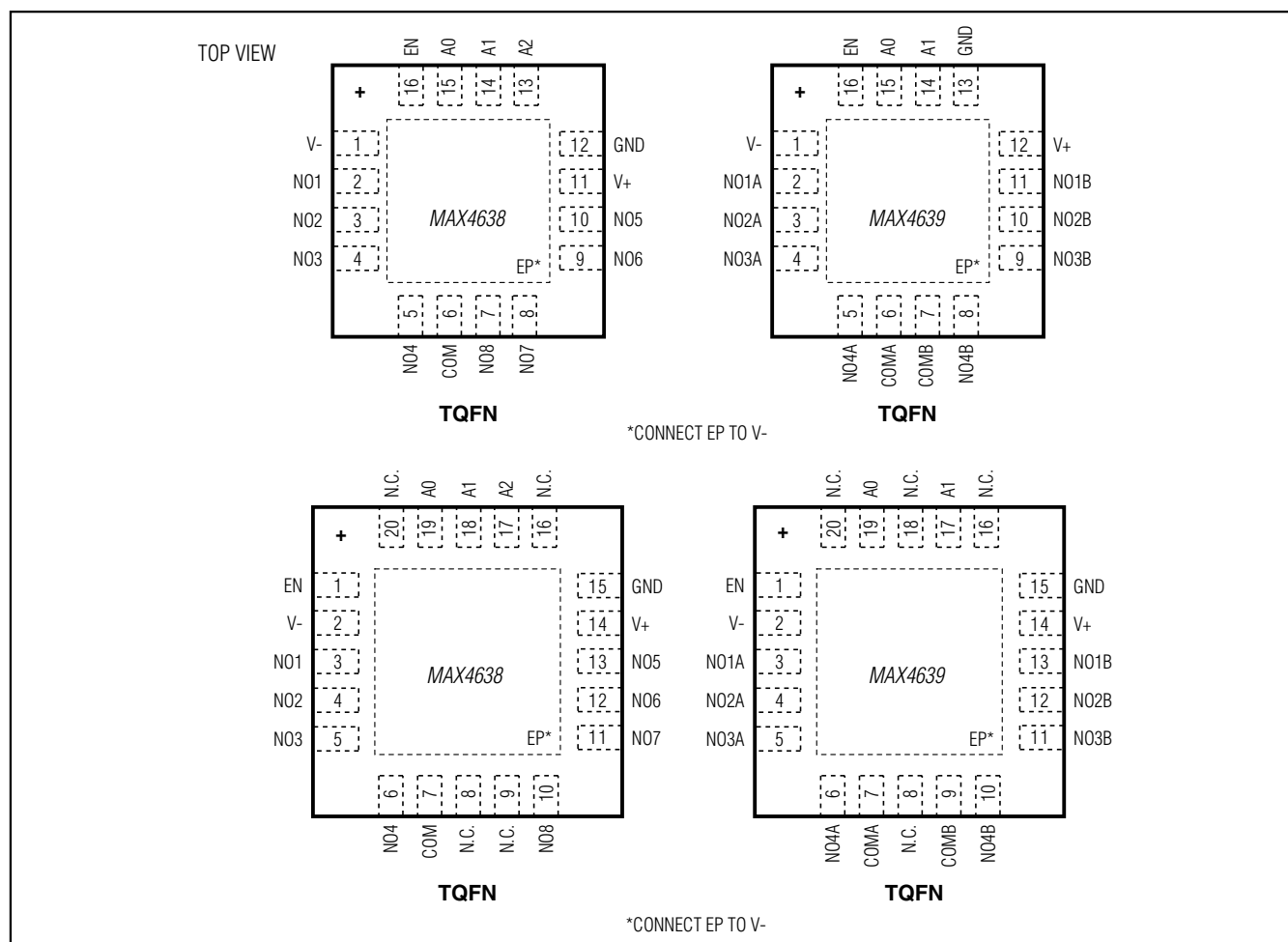


Figure 8. Channel Off/On-Capacitance

MAX4638/MAX4639

3.5Ω, Single 8:1 and Dual 4:1, Low-Voltage Analog Multiplexers

Pin Configurations (continued)



Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
MAX4639ETE+T	-40°C to +85°C	16 TQFN-EP* (4 × 4)
MAX4639EUE+T	-40°C to +85°C	16 TSSOP
MAX4639ESE+T	-40°C to +85°C	16 SO
MAX4639ETP+T	-40°C to +85°C	20 TQFN-EP* (4 × 4)

+Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

*EP = Exposed pad.

Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
16 TQFN	T1644+4	21-0139	90-0070
20 TQFN	T1644+3	21-0139	90-0069
16 TSSOP	U16+2	21-0066	90-0117
16 SO	S16+3	21-0041	90-0097

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3.5Ω, Single 8:1 and Dual 4:1,Z Low-Voltage Analog Multiplexers

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
2	9/10	—	—
3	10/12	Added RoHS ordering information throughout data sheet	1–16



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